Analog Switch

HITACHI

ADE-205-308D (Z)

5th Edition May 2001

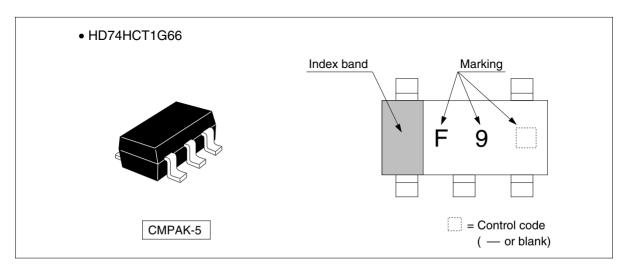
Description

The HD74HCT1G66 is high speed CMOS analog switch using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed. The device has low ON resistance for good transfer characteristics and can take wide range of input voltage.

Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Control input is TTL compatible input level.
 Supply voltage range: 4.5 to 5.5 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$

Outline and Article Indication



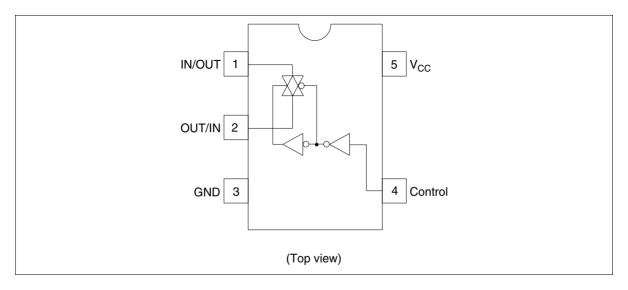


Function Table

| Control | Switch |
|---------|--------|
| L | OFF |
| Н | ON |

H: High level
L: Low level
GND \leq V_{IN} \leq V_{CC}
GND \leq V_{OUT} \leq V_{CC}

Pin Arrangement



Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Test Conditions |
|--|-------------------------------------|--------------------------|------|---|
| Supply voltage range | V _{CC} | -0.5 to 7.0 | V | |
| Input voltage range *1 | Vı | -0.5 to V_{CC} + 0.5 | V | |
| Output voltage range *1,2 | V _o | -0.5 to V_{CC} + 0.5 | V | Output : H or L |
| Input clamp current | I _{IK} | ±20 | mA | $V_i < 0$ or $V_i > V_{CC}$ |
| Output clamp current | I _{OK} | ±20 | mA | $V_{\rm O}$ < 0 or $V_{\rm O}$ > $V_{\rm CC}$ |
| Continuous output current | Io | ±25 | mA | $V_{\rm O}$ = 0 to $V_{\rm CC}$ |
| Continuous current through V _{CC} or GND | I _{CC} or I _{GND} | ±25 | mA | |
| Maximum power dissipation at Ta = 25°C (in still air) *3 | P _T | 200 | mW | |
| Storage temperature | Tstg | –65 to 150 | °C | |

Notes:

The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was caluculated using a junction temperature of 150°C.

Recommended Operating Conditions

| Item | Symbol | Min | Max | Unit | Test Conditions |
|--|---------------------------------|-----|-----------------|------|-------------------------|
| Supply voltage range | V _{CC} | 4.5 | 5.5 | V | |
| Input voltage range | V _I | 0 | 5.5 | V | |
| Output voltage range | V _{I/O} | 0 | V _{cc} | V | |
| Input rise / fall time (Control input 0.3 V to 2.7 V) | t _r , t _f | 0 | 500 | ns | V_{cc} = 4.5 to 5.5 V |
| Operating temperature | Та | -40 | 85 | °C | |

Note: Unused or floating control inputs must be held high or low.

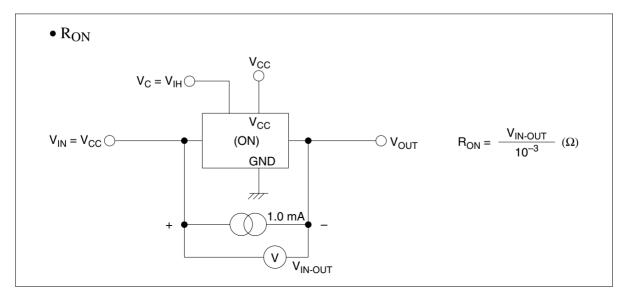
Electrical Characteristics

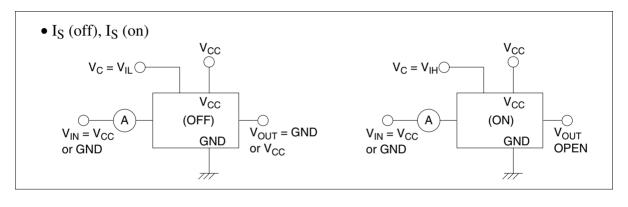
| | | \mathbf{V}_{cc} | Ta = 2 | 5°C | | Ta = -40 to 85°C | | | |
|--------------------------|----------------------|-------------------|--------|-----|------|------------------|------|------|---|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit | Test Conditions |
| Input voltage | V _{IH} | 4.5 to 5.5 | 2.0 | _ | _ | 2.0 | _ | V | Control input only |
| | V _{IL} | 4.5 to 5.5 | _ | _ | 0.8 | _ | 0.8 | - | |
| On resistance | R _{on} | 4.5 to 5.5 | _ | 90 | 160 | _ | 180 | Ω | $V_C = V_{IH}$ $V_{IN} = V_{CC}$ or GND $I_T = 1 \text{ mA}$ |
| Peak on resistance | R _{on} (p) | 4.5 to 5.5 | _ | 125 | 200 | _ | 250 | Ω | $V_C = V_{IH}$ $V_{IN} = 0$ to V_{CC} $I_{IN/OUT} = 1$ mA |
| Leak current | I _S (off) | 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μА | $V_{C} = V_{IL}$ $V_{IN} = V_{CC}, V_{OUT} = GND$ or $V_{IN} = GND, V_{OUT} =$ V_{CC} |
| | I _S (on) | 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μА | $V_C = V_{IH}$ $V_{IN} = V_{CC}$ or GND |
| Input current | I _{IN} | 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μА | V _{IN} = V _{CC} or GND |
| Operating current | I _{cc} | 5.5 | _ | _ | 1.0 | _ | 10.0 | μА | $V_{IN} = V_{CC}$ or GND |
| Quiescent supply current | I _{CCT} | 5.5 | _ | _ | 2.0 | _ | 2.9 | mA | $V_C = 2.4 \text{ V},$ $V_{IN} \text{ (switch)} = V_{CC} \text{ or }$ GND |

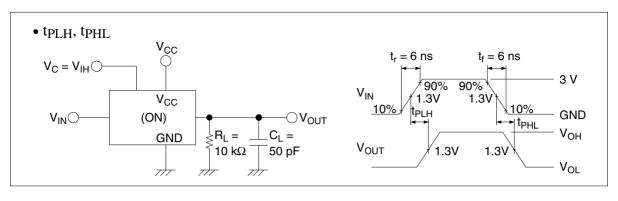
Switching Characteristics

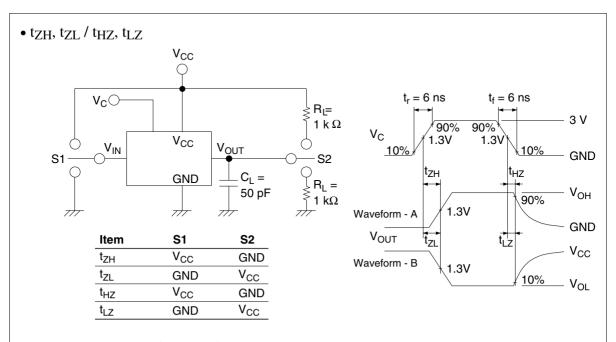
| | | \mathbf{V}_{cc} | Ta = 2 | 25°C | | Ta = -4 | 40 to 85°C | | |
|-------------------------------|---------------------|-------------------|--------|------|-----|---------|------------|------|----------------------------|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit | Test Conditions |
| Propagation delay time | t_{PLH},t_{PHL} | 4.5 | _ | 4 | 10 | _ | 13 | ns | $R_L = 10 \text{ k}\Omega$ |
| Output enable time | t_{ZH}, t_{ZL} | 4.5 | _ | 10 | 23 | _ | 29 | ns | R _L = 1 kΩ |
| Output disable time | t_{HZ}, t_{LZ} | 4.5 | _ | 14 | 23 | _ | 29 | ns | $R_L = 1 k\Omega$ |
| Maximum control frequency | | 4.5 | _ | 30 | _ | _ | _ | MHz | |
| Control input capacitance | C _{IN} | | _ | 2.5 | 5 | _ | 5 | pF | |
| Switch I/O capacitance | C _{IN/OUT} | | _ | 2.5 | _ | _ | _ | pF | |
| Feed through capacitance | C _{IN-OUT} | | _ | 0.5 | _ | _ | _ | pF | |
| Power dissipation capacitance | C_{PD} | | _ | 5 | _ | _ | _ | pF | |

Test Circuit



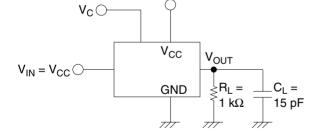


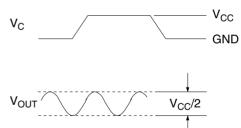




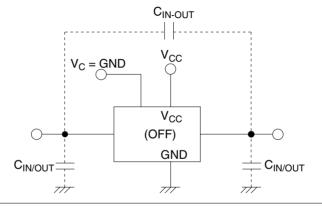
- Notes: 1. Waveform A is for an output with internal conditions such that the output is high except when disabled by the output control.
 - 2. Waveform B is for an output with internal conditions such that the output is low except when disabled by the output control.

Maximum control frequency V_{CC}

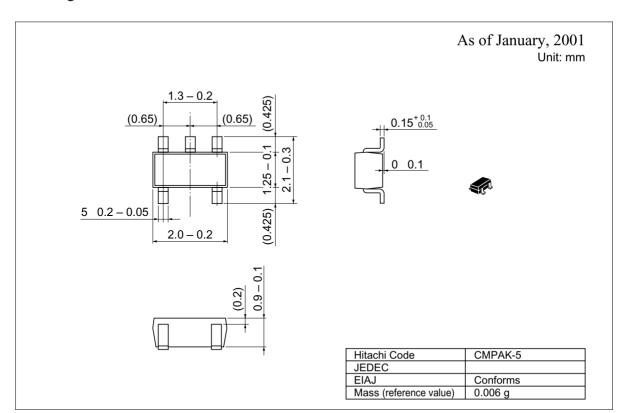




• C_{IN/OUT}, C_{IN-OUT}



Package Dimensions



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